TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7MH595FK

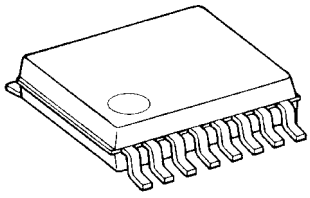
8-Bit Shift Register/Latch (3-State)

The TC7MH595FK is an advanced high speed 8 bit shift register/latch fabricated with silicon gate C^2MOS technology.

It achieves the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

The TC7MH595FK contains an 8 bit static shift register which feeds an 8 bit storage register.

Shift operation is accomplished on the positive going transition of the SCK input. The output register is loaded with the contents of the shift register on the positive going transition of the RCK input. Since RCK and SCK signals are independent, parallel outputs can be held stable during the shift operation. And, since the parallel outputs are 3-state, it can be directly connected to 8 bit bus. This register can be used in serial-to-parallel conversion, data receivers, etc.



VSSOP16-P-0030-0.50

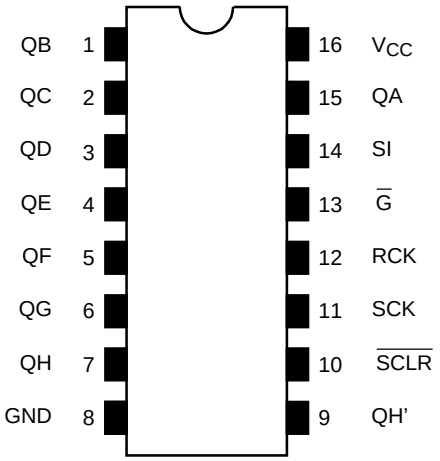
Weight: 0.02 g (typ.)

An input protection circuit ensures that 0 to 7 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

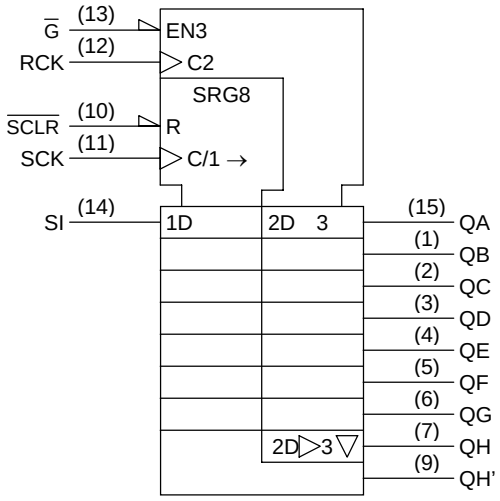
Features

- High speed: f_{max} = 185 MHz (typ.) (V_{CC} = 5 V)
- Low power dissipation: I_{CC} = 4 μA (max) (Ta = 25°C)
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range: $V_{CC\ (opr)}$ = 2~5.5 V
- Low noise: V_{OLP} = 1.0 V (max)
- Pin and function compatible with 74ALS595

Pin Assignment (top view)



IEC Logic Symbol

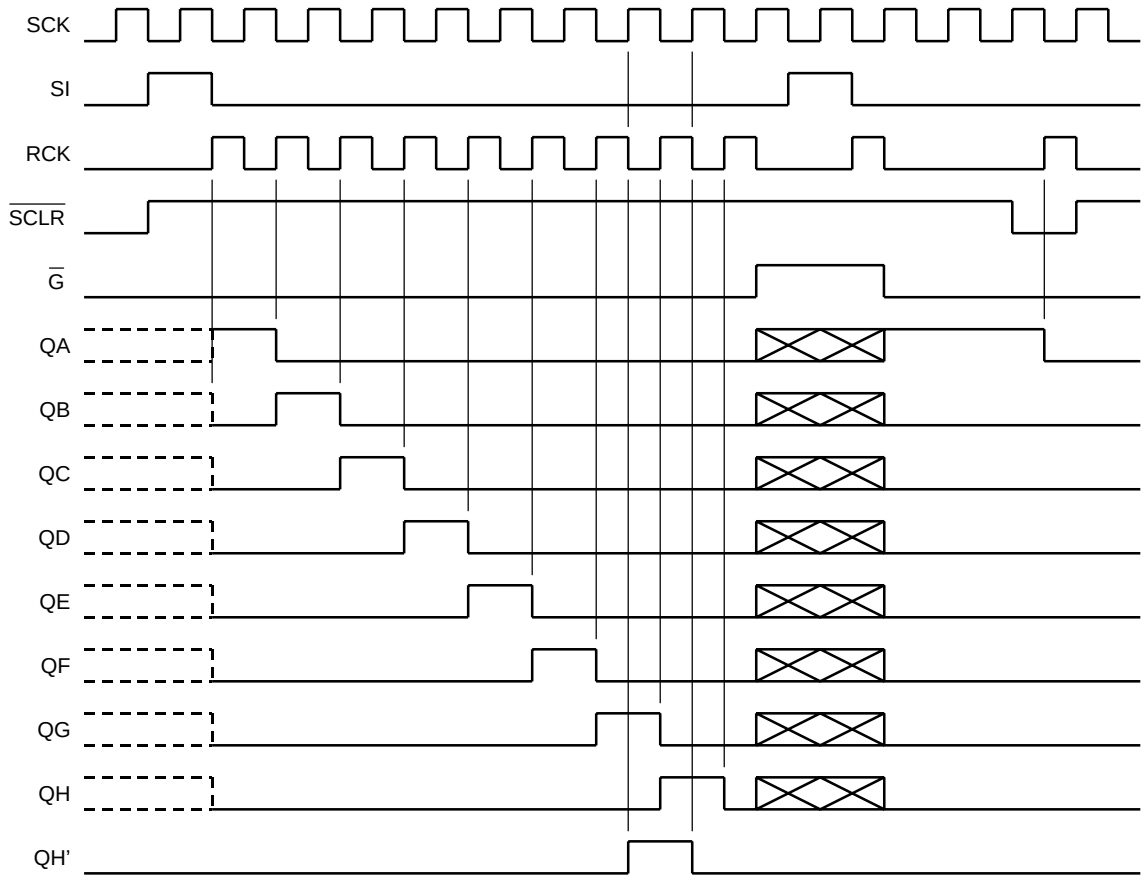


Truth Table

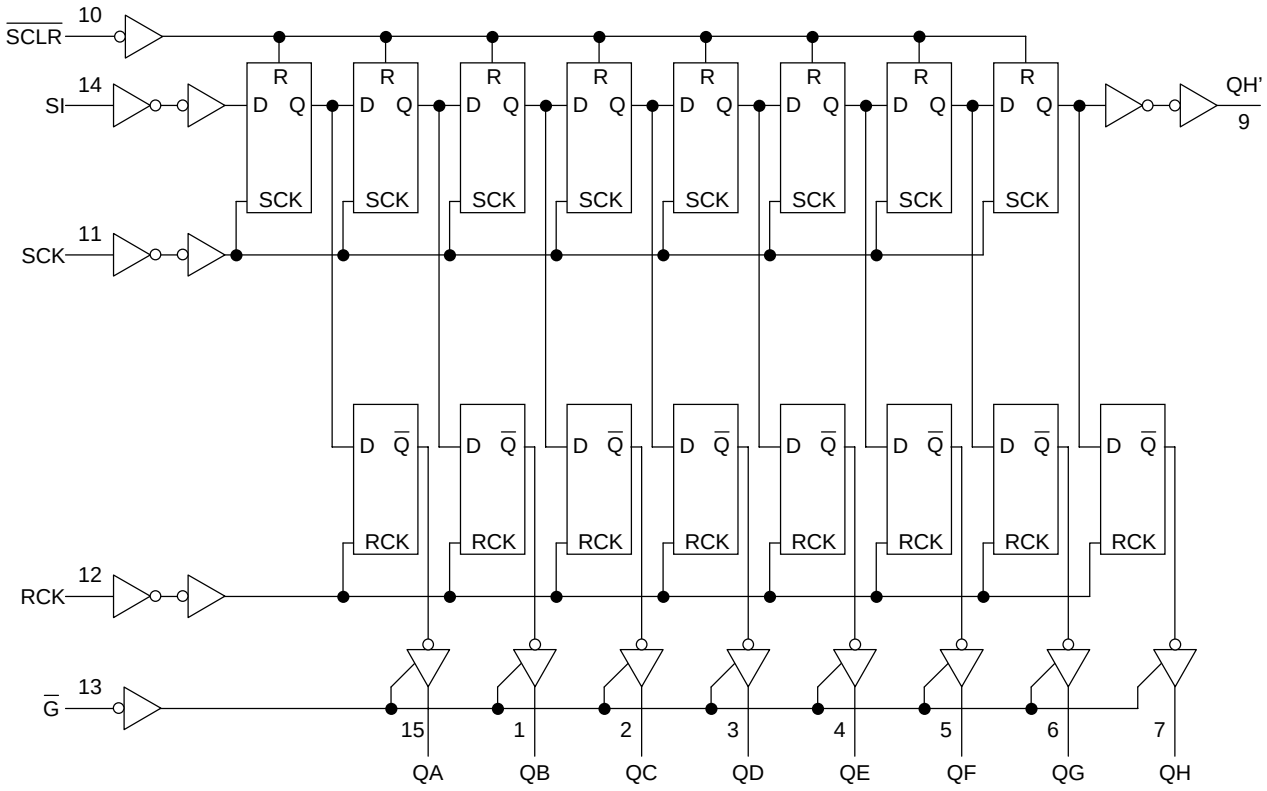
Inputs					Function
SI	SCK	$\overline{SCLR}$	RCK	$\overline{G}$	
X	X	X	X	H	QA thru QH outputs disable
X	X	X	X	L	QA thru QH outputs enable
X	X	L	X	X	Shift register is cleared.
L	↑	H	X	X	First stage of S.R. becomes “L”. Other stages store the data of previous stage, respectively.
H	↑	H	X	X	First stage of S.R. becomes “H”. Other stages store the data of previous stage, respectively.
X	↓	H	X	X	State of S.R. is not changed.
X	X	X	↑	X	S.R. data is stored into storage register.
X	X	X	↓	X	Storage register stage is not changed.

X: Don’t care

Timing Chart



System Diagram



Maximum Ratings

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5~7.0	V
DC input voltage	V_{IN}	−0.5~7.0	V
DC output voltage	V_{OUT}	−0.5~V_{CC} + 0.5	V
Input diode current	I_{IK}	−20	mA
Output diode current	I_{OK}	±20	mA
DC output current	I_{OUT}	±25	mA
DC V_{CC}/ground current	I_{CC}	±75	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	−65~150	°C

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0~5.5	V
Input voltage	V_{IN}	0~5.5	V
Output voltage	V_{OUT}	0~V_{CC}	V
Operating temperature	T_{opr}	−40~85	°C
Input rise and fall time	dt/dv	0~100 (V_{CC} = 3.3 ± 0.3 V)	ns/V
		0~20 (V_{CC} = 5 ± 0.5 V)	

Electrical Characteristics

DC Characteristics

Characteristics		Symbol	Test Condition		V_{CC} (V)	Ta = 25°C Min	Ta = 25°C Typ.	Ta = 25°C Max	Ta = −40~85°C Min	Ta = −40~85°C Max	Unit
Input voltage	High level	V_{IH}	—		2.0	1.50	—	—	1.50	—	V
					3.0~5.5	$V_{CC} \times 0.7$	—	—	$V_{CC} \times 0.7$	—	
	Low level	V_{IL}	—		2.0	—	—	0.50	—	0.50	
					3.0~5.5	—	—	$V_{CC} \times 0.3$	—	$V_{CC} \times 0.3$	
Output voltage	High level	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -50$ μA	2.0	1.9	2.0	—	1.9	—	V
					3.0	2.9	3.0	—	2.9	—	
					4.5	4.4	4.5	—	4.4	—	
				$I_{OH} = -4$ mA	3.0	2.58	—	—	2.48	—	
				$I_{OH} = -8$ mA	4.5	3.94	—	—	3.80	—	
	Low level	V_{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 50$ μA	2.0	—	0	0.1	—	0.1	
					3.0	—	0	0.1	—	0.1	
					4.5	—	0	0.1	—	0.1	
				$I_{OL} = 4$ mA	3.0	—	—	0.36	—	0.44	
				$I_{OL} = 8$ mA	4.5	—	—	0.36	—	0.44	
3-state output off-state current		I_{OZ}	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = V_{CC}$ or GND		5.5	—	—	±0.25	—	±2.50	μA
Input leakage current		I_{IN}	$V_{IN} = 5.5$ V or GND		0~5.5	—	—	±0.1	—	±1.0	μA
Quiescent supply current		I_{CC}	$V_{IN} = V_{CC}$ or GND		5.5	—	—	4.0	—	40.0	μA

Timing Requirements (Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V_{CC} (V)	Ta = 25°C Typ.	Ta = 25°C Limit	Ta = −40~85°C Limit	Unit
Minimum pulse width (SCK, RCK)	$t_{w(H)}$ $t_{w(L)}$	—	3.3 ± 0.3	—	5.0	5.0	ns
			5.0 ± 0.5	—	5.0	5.0	
Minimum pulse width ($\overline{SCLR}$)	$t_{w(L)}$	—	3.3 ± 0.3	—	5.0	5.0	ns
			5.0 ± 0.5	—	5.0	5.0	
Minimum set-up time (SI-SCK)	t_s	—	3.3 ± 0.3	—	3.5	3.5	ns
			5.0 ± 0.5	—	3.0	3.0	
Minimum set-up time (SCK-RCK)	t_s	—	3.3 ± 0.3	—	8.0	8.5	ns
			5.0 ± 0.5	—	5.0	5.0	
Minimum set-up time ($\overline{SCLR}$ -RCK)	t_s	—	3.3 ± 0.3	—	8.0	9.0	ns
			5.0 ± 0.5	—	5.0	5.0	
Minimum hold time (SI-SCK)	t_h	—	3.3 ± 0.3	—	1.5	1.5	ns
			5.0 ± 0.5	—	2.0	2.0	
Minimum hold time (SCK-RCK, $\overline{SCLR}$ -RCK)	t_h	—	3.3 ± 0.3	—	0	0	ns
			5.0 ± 0.5	—	0	0	
Minimum removal time ($\overline{SCLR}$)	t_{rem}	—	3.3 ± 0.3	—	3.0	3.0	ns
			5.0 ± 0.5	—	2.5	2.5	

AC Characteristics (Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40~85°C		Unit
			V_{CC} (V)	C_L (pF)	Min	Typ.	Max	Min	Max	
Propagation delay time (SCK-QH')	t_{pLH} t_{pHL}	—	3.3 ± 0.3	15	—	8.8	13.0	1.0	15.0	ns
				50	—	11.3	16.5	1.0	18.5	
			5.0 ± 0.5	15	—	6.2	8.2	1.0	9.4	
				50	—	7.7	10.2	1.0	11.4	
Propagation delay time ($\overline{SCLR}$ -QH')	t_{pHL}	—	3.3 ± 0.3	15	—	8.4	12.8	1.0	13.7	ns
				50	—	10.9	16.3	1.0	17.2	
			5.0 ± 0.5	15	—	5.9	8.0	1.0	9.1	
				50	—	7.4	10.0	1.0	11.1	
Propagation delay time (RCK-Q_n)	t_{pLH} t_{pHL}	—	3.3 ± 0.3	15	—	7.7	11.9	1.0	13.5	ns
				50	—	10.2	15.4	1.0	17.0	
			5.0 ± 0.5	15	—	5.4	7.4	1.0	8.5	
				50	—	6.9	9.4	1.0	10.5	
Output enable time	t_{pZL} t_{pZH}	R_L = 1 kΩ	3.3 ± 0.3	15	—	7.5	11.5	1.0	13.5	ns
				50	—	9.0	15.0	1.0	17.0	
			5.0 ± 0.5	15	—	4.8	8.6	1.0	10.0	
				50	—	8.3	10.6	1.0	12.0	
Output disable time	t_{pLZ} t_{pHZ}	R_L = 1 kΩ	3.3 ± 0.3	50	—	12.1	15.7	1.0	16.2	ns
			5.0 ± 0.5	50	—	7.6	10.3	1.0	11.0	
Maximum clock frequency	f_{max}	—	3.3 ± 0.3	15	80	150	—	70	—	MHz
				50	55	130	—	50	—	
			5.0 ± 0.5	15	135	185	—	115	—	
				50	95	155	—	85	—	
Input capacitance	C_{IN}	—			—	4	10	—	10	pF
Output capacitance	C_{OUT}	—			—	6	—	—	—	pF
Power dissipation capacitance	C_{PD}	(Note)			—	87	—	—	—	pF

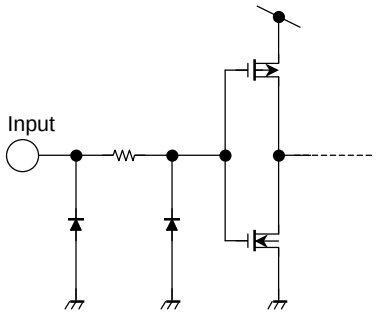
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.
Average operating current can be obtained by the equation:

$I_{CC\ (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Noise Characteristics (Input: $t_r = t_f = 3$ ns)

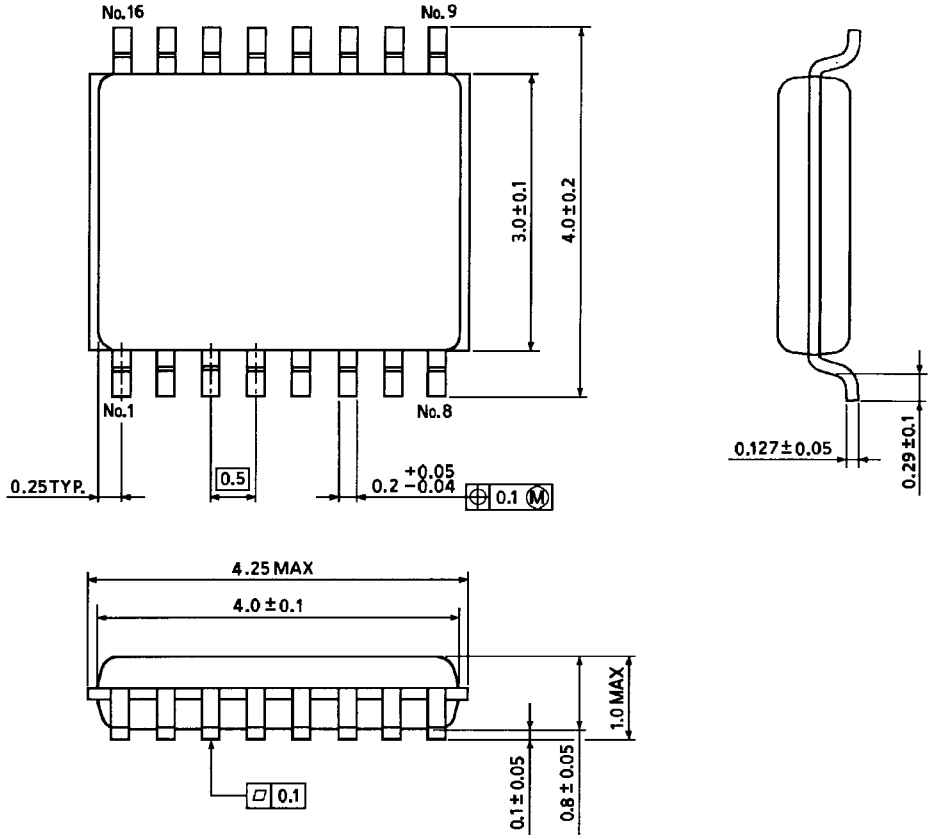
Characteristics	Symbol	Test Condition	Ta = 25°C			Unit
			V_{CC} (V)	Typ.	Limit	
Quiet output maximum dynamic V_{OL}	V_{OLP}	C_L = 50 pF	5.0	0.8	1.0	V
Quiet output minimum dynamic V_{OL}	V_{OLV}	C_L = 50 pF	5.0	−0.8	−1.0	V
Minimum high level dynamic input voltage VIH	V_{IHD}	C_L = 50 pF	5.0	—	3.5	V
Maximum low level dynamic input voltage VIL	V_{ILD}	C_L = 50 pF	5.0	—	1.5	V

Input Equivalent Circuit



Package Dimensions

VSSOP16-P-0030-0.50 Unit : mm



Weight: 0.02 g (typ.)

RESTRICTIONS ON PRODUCT USE

000707EBA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
  In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the “Handling Guide for Semiconductor Devices,” or “TOSHIBA Semiconductor Reliability Handbook” etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury (“Unintended Usage”). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer’s own risk.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.